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APPLICATION NO.	FILING DATE	FIRST NAMED II	VENTOR		303.522US1	
09/382.442 021186 9CHWEGMAN. P.O. BOX 2 MINNEAPOLI	LUNDBERG. 938	MM92/1103 WOESSNER & KLUTH	٦	BOOTH ART UNIT 2812 DATE MAILE	EXAMINER  I. F: PAPER NUMBER	] ]

Please find below and/or attached an Office communication concerning this application or proceeding.

**Commissioner of Patents and Trademarks** 

	Application No.		Applicant(s)	
			REINBERG, A	LAN R.
	09/382,442		Art Unit	
Office Action Summary	Examiner		2812	
The MAILING DATE of this communication app	Richard A. Booth	choot with t	he correspondence	address
The MAILING DATE of this communication app	pears on the cover	Meet will t	•	
riod for Reply	. VIO CET TO EY	PIRE 3 MO	NTH(S) FROM	
A SHORTENED STATUTORY PERIOD FOR INC.  THE MAILING DATE OF THIS COMMUNICATION  THE MAILING DATE may be available under the provisions of the communication o	37 CFR 1.136 (a). In n	o event, nowe	mum of thirty (30) days	ely filed will
If NO period for reply is specified above, the maximum states communication.     Failure to reply within the set or extended period for reply within the set.	ill, by statute, cause the	nd will expire s	SIX (6) MONTHS from to become ABANDONE	D (35 U.S.C. § 133).
1) Responsive to communication(s) filed on _ 2a) This action is FINAL. 2b)  3) Since this application is in condition for all closed in accordance with the practice unit	Tills dottor		tters, prosecution a D. 11, 453 O.G. 21	as to the merits is 3.
Disposition of Claims  4) ◯ Claim(s) 1-39 is/are pending in the application 4a) Of the above claim(s) 15-25,33 and 34  5) ◯ Claim(s) is/are allowed.  6) ◯ Claim(s) 1-14, 26-32, and 35-39 is/are rejection 5.  7) ◯ Claim(s) is/are objected to.  8) ◯ Claims are subject to restriction 5.	jected.		deration.	
Application Papers  9) The specification is objected to by the Example 10) The drawing(s) filed on is/are objected to by the Example 11) The proposed drawing correction filed on The oath or declaration is objected to by	n is: a)□ a	aminer. pproved b	)∐ disapproved.	·
Priority under 35 U.S.C. § 119  13) Acknowledgment is made of a claim for a) All b) Some * c) None of the control of the contr				ve been:
<ul> <li>1. received.</li> <li>2. received in Application No. (Ser</li> <li>3. received in this National Stage at the attached detailed Office action</li> </ul>	for a list of the cert	ified copies	not received.	tule 17.2(a)).
* See the attached detailed Office action  14) Acknowledgement is made of a claim	TOL COMESTIC SHOW	•		
Attachment(s)  15) Notice of References Cited (PTO-892)  16) Notice of Draftsperson's Patent Drawing Review (PTO-1449) Properties Statement(s) (PTO-1449) Properties Review (PTO-1449) Propert	PTO-948)	19) 🔲 N	terview Summary (PTC otice of Informal Paten ther:	)-413) Paper No(s) Application (PTO-152)
16) Notice of Draftsperson's Patent Drawing Review (17) Information Disclosure Statement(s) (PTO-1449) P	три пост			Part of Paper N

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## **DETAILED ACTION**

### Election/Restrictions

Applicant's election without traverse of group I in Paper No. 4 is acknowledged.

## Claim Rejections - 35 USC § 112

The following is a quotation of the second paragraph of 35 U.S.C. 112:

The specification shall conclude with one or more claims particularly pointing out and distinctly claiming the subject matter which the applicant regards as his invention.

Claim 6 is rejected under 35 U.S.C. 112, second paragraph, as being indefinite for failing to particularly point out and distinctly claim the subject matter which applicant regards as the invention.

In claim 6, the phrase "the semiconductor" lacks antecedent basis.

# Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 1-14, 26-32, and 35-38 are rejected under 35 U.S.C. 103(a) as being unpatentable over Lisenker et al., PCT WO 94/19829.

Lisenker et al. shows the invention substantially as claimed including forming a MOS based device whereby deuterium is employed at various stages of the process to, for instance, gate oxides, field oxides, and various other oxide layers (see page 4, lines 24-32). In addition, deuterium can be employed in many processes (see page 8, lines

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30-35). In fact, deuterium can be used in any process in which hydrogen or a hydrogen . Art Unit: 2812 containing compound is used.

Lisenker et al. lacks anticipation of specifically performing the deuterium processes on a flash memory device. However, a flash memory device is a MOS based device and therefore it would have been obvious to one of ordinary skill in the art at the time the invention was made to perform the deuterium processing disclosed in the primary reference of Lisenker et al. on a flash memory device because the beneficial results would also occur on a flash memory. Furthermore, the examiner takes official notice that the process steps claimed are well known in the art hydrogen based processes and would have been prima facie obvious to replace the hydrogen with deuterium for the reasons suggested by Lisenker et al..

Claim 39 is rejected under 35 U.S.C. 103(a) as being unpatentable over Lisenker et al. as applied to claims 1-5, 7-14, 26-32, and 35-38 above, and further in view of Aomori et al., U.S. Patent 5,504,020.

Lisenker et al. is applied as above but lacks anticipation of defining the source and drain using deuterium implantation.

Aomori et al. discloses performing hydrogen implantation using the gate as a mask to simultaneously perform source and drain implantation and hydrogenation which leads to a stable substrate interface (see column 9, line 65 – column 10, line 14 and abstract). In view of this disclosure, it would have been obvious to one of ordinary skill in the art at the time the invention was made to perform the process disclosed by Aomori et al. using deuterium instead of hydrogen because the overall processing steps Application/Control Number: 09/382,442

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are reduced and deuterium has beneficial results compared to hydrogen as advanced by Linsenker et al..

#### Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Richard A. Booth whose telephone number is 308-3446. The examiner can normally be reached on Monday to Thursday from 7:30 to 6:00

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, John Niebling can be reached on 308-3325. The fax phone numbers for the organization where this application or proceeding is assigned are 308-7724 for regular communications and 308-7724 for After Final communications.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is 308-1782.

Richard A. Booth Art Unit 2812